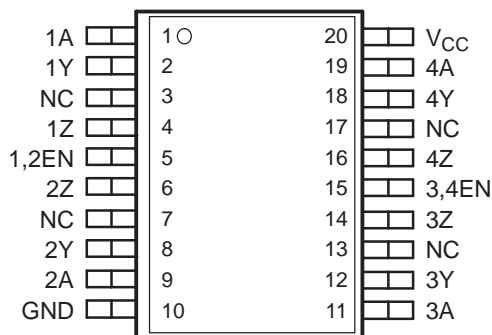


FEATURES

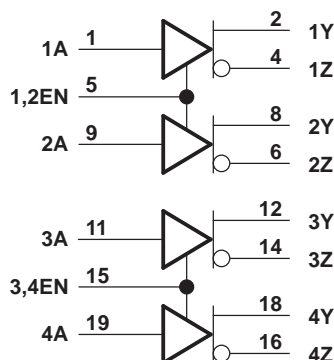
- **Controlled Baseline**
 - One Assembly/Test Site, One Fabrication Site
- **Extended Temperature Performance of –55°C to 125°C**
- **Enhanced Diminishing Manufacturing Sources (DMS) Support**
- **Enhanced Product-Change Notification**
- **Qualification Pedigree ⁽¹⁾**
- **Designed for TIA/EIA-485, TIA/EIA-422, and ISO 8482 Applications**
- **Signaling Rates up to 30 Mbps ⁽²⁾**
- **Propagation Delay Times <11 ns**
- **Low Standby Power Consumption 1.5 mA Max**
- **Output ESD Protection Exceeds 13 kV**
- **Driver Positive- and Negative-Current Limiting**
- **Power-Up and Power-Down Glitch Free for Line-Insertion Applications**
- **Thermal Shutdown Protection**
- **Industry Standard Pinout, Compatible With SN75174, MC3487, DS96174, LTC487, and MAX3042**

- (1) Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.
- (2) The signaling rate of a line is the number of voltage transitions that are made per second, expressed in the unit bits per second (bps).

20-PIN DW PACKAGE
(TOP VIEW)



logic diagram (positive logic)



DESCRIPTION/ORDERING INFORMATION

The SN65LBC174A-EP is a quadruple differential line driver with 3-state outputs, designed for TIA/EIA-485 (RS-485), TIA/EIA-422 (RS-422), and ISO 8482 applications.

This device is optimized for balanced multipoint bus transmission at signaling rates up to 30-million bits per second (Mbps). The transmission media may be printed-circuit-board traces, backplanes, or cables. The ultimate rate and distance of data transfer is dependent upon the attenuation characteristics of the media and the noise coupling to the environment.

Each driver features current limiting and thermal-shutdown circuitry, making it suitable for high-speed multipoint applications in noisy environments. The device is designed using LinBiCMOS™ technology, facilitating low power consumption and robustness.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

LinBiCMOS is a trademark of Texas Instruments.

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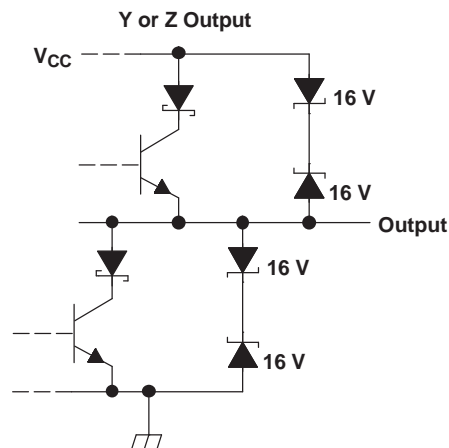
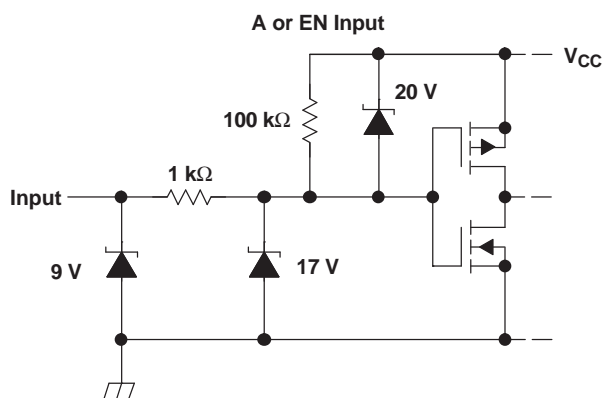
ORDERING INFORMATION

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE⁽¹⁾
(each driver)

(1) H = high level, L = low level, X = irrelevant,
Z = high impedance (off)

EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS



Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range ⁽²⁾		−0.3	6	V
	Voltage range at any bus (dc)		−10	15	V
	Voltage range at any bus (transient pulse through 100 Ω , see Figure 8)		−30	30	V
V_I	Input voltage range at any A or EN terminal		−0.5	$V_{CC} + 0.5$	V
Electrostatic discharge	Human-Body Model ⁽³⁾	Y, Z, and GND		13	kV
		All pins		5	
	Charged-Device Model ⁽⁴⁾	All pins		1	
T_{stg}	Storage temperature range ⁽⁵⁾		−65	150	°C
	Continuous power dissipation		See Dissipation Rating Table		
	Lead temperature 1,6 mm (1/16 in) from case for 10 s			260	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential I/O bus voltages, are with respect to GND.
- (3) Tested in accordance with JEDEC standard 22, Test Method A114-A.
- (4) Tested in accordance with JEDEC standard 22, Test Method C101.
- (5) Long-term high-temperature storage and/or extended use at maximum recommended operating conditions may result in a reduction of overall device life. See http://www.ti.com/ep_quality for additional information on enhanced plastic packaging.

DISSIPATION RATING TABLE

PACKAGE	JEDEC BOARD MODEL	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ⁽¹⁾ ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
20-pin DW	Low K	1483 mW	11.86 mW/°C	949 mW	297 mW
	High K	2753 mW	22 mW/°C	1762 mW	553 mW

- (1) This is the inverse of the junction-to-ambient thermal resistance when board mounted with no air flow.

SN65LBC174A-EP

QUADRUPLE RS-485 DIFFERENTIAL LINE DRIVER

SLLS732–OCTOBER 2006–REVISED DECEMBER 2006

Recommended Operating Conditions

			MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage		4.75	5	5.25	V
	Voltage at any bus terminal	Y, Z	–7		12	V
V_{IH}	High-level input voltage	A, EN	2		V_{CC}	V
V_{IL}	Low-level input voltage	A, EN	0		0.8	V
	Output current		–60		60	mA
T_A	Operating free-air temperature		–55		125	°C

Electrical Characteristics

over recommended operating conditions

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT	
V _{IK}	Input clamp voltage	I _I = −18 mA		−1.5	−0.77		V	
V _O	Open-circuit output voltage	Y or Z, No load		0		V _{CC}	V	
V _{OD(SS)}	Steady-state differential output voltage magnitude ⁽²⁾	No load (open circuit)		3		V _{CC}	V	
		R _L = 54 Ω, See Figure 1		0.8	1.6	2.5		
		With common-mode loading, See Figure 2		0.8	1.6	2.5		
ΔV _{OD(SS)}	Change in steady-state differential output voltage between logic states	See Figure 1		−0.1		0.1	V	
V _{OC(SS)}	Steady-state common-mode output voltage	See Figure 3		2	2.4	2.8	V	
ΔV _{OC(SS)}	Change in steady-state common-mode output voltage between logic states	See Figure 3		−0.04		0.04	V	
I _I	Input current	A, G, \overline{G}		−70		70	μA	
I _{OS}	Short-circuit output current	V _{TEST} = −7 V to 12 V, See Figure 7	V _I = 0 V	−200		200	mA	
			V _I = V _{CC}					
I _{OZ}	High-impedance-state output current			EN at 0 V	−50		50	μA
I _{O(OFF)}	Output current with power off			V _{CC} = 0 V	−10		10	
I _{CC}	Supply current	V _I = 0 V or V _{CC} , No load	All drivers enabled			25	mA	
			All drivers disabled			1.5		

(1) All typical values are at $V_{CC} = 5$ V and 25°C.

(2) The minimum V_{OD} may not fully comply with TIA/EIA-485-A at operating temperatures below 0°C. System designers should take the possibility of lower output signal into account in determining the maximum signal transmission distance.

Switching Characteristics

over recommended operating conditions

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
t _{PLH}	Propagation delay time, low- to high-level output	R _L = 54 Ω, C _L = 50 pF, See Figure 4	T _A =25°C	4.0	8	11	ns
			T _A = -55°C to 125°C	4.0		16	ns
t _{PHL}	Propagation delay time, high- to low-level output		T _A =25°C	4.0	8	11	ns
			T _A = -55°C to 125°C	4.0		16	ns
t _r	Differential output voltage rise time		T _A =25°C	3	7.5	11	ns
			T _A = -55°C to 125°C	3		24	ns
t _f	Differential output voltage fall time		T _A =25°C	3	7.5	11	ns
			T _A = -55°C to 125°C	3		24	ns
t _{sk(p)}	Pulse skew t _{PLH} – t _{PHL}				0.6		ns
					0.6		
t _{sk(o)}	Output skew ⁽¹⁾			2		ns	
t _{sk(pp)}	Part-to-part skew ⁽²⁾			3		ns	
t _{PZH}	Propagation delay time, high impedance to high-level output	See Figure 5				25	ns
t _{PHZ}	Propagation delay time, high-level output to high impedance					25	ns
t _{PZL}	Propagation delay time, high impedance to low-level output	See Figure 6				30	ns
t _{PLZ}	Propagation delay time, low-level output to high impedance					20	ns

- (1) Output skew ($t_{sk(o)}$) is the magnitude of the time delay difference between the outputs of a single device with all of the inputs connected together.
- (2) Part-to-part skew ($t_{sk(pp)}$) is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same input signals, the same supply voltages, at the same temperature, and have identical packages and test circuits.

PARAMETER MEASUREMENT INFORMATION

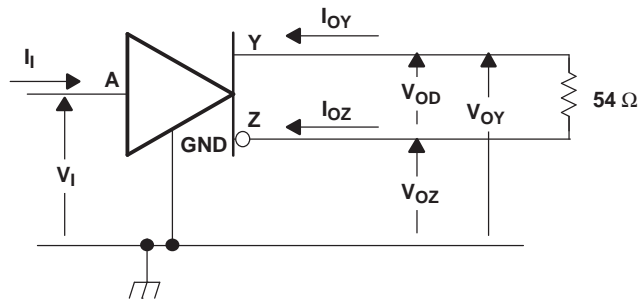


Figure 1. Test Circuit, V_{OD} Without Common-Mode Loading

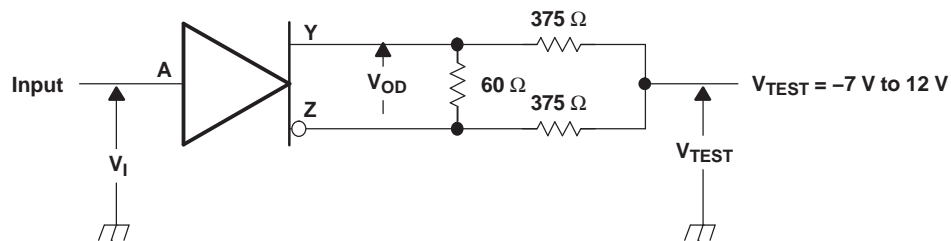
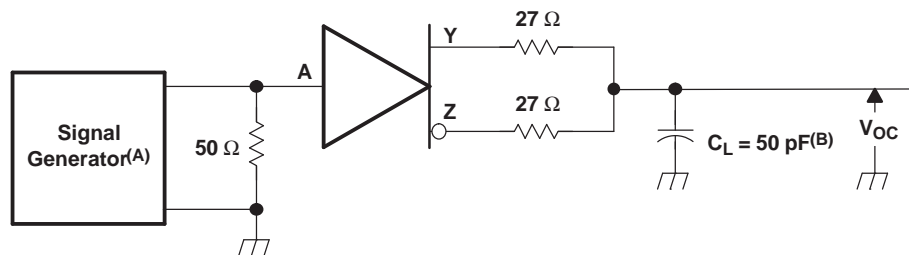


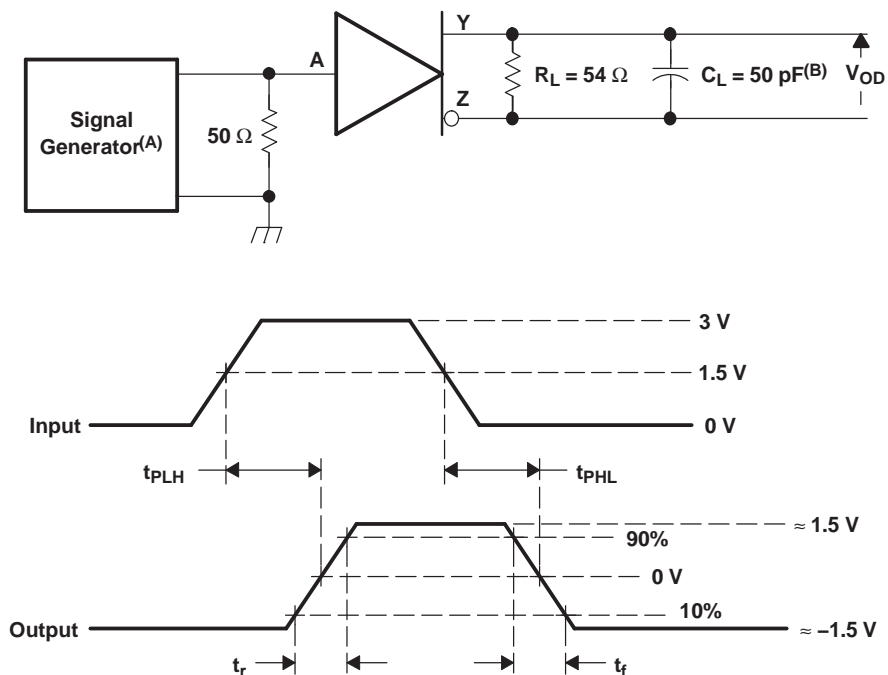
Figure 2. Test Circuit, V_{OD} With Common-Mode Loading



- A. PRR = 1 MHz, 50% duty cycle, $t_r < 6$ ns, $t_f < 6$ ns, $Z_O = 50 \Omega$
- B. Includes probe and jig capacitance

Figure 3. V_{OC} Test Circuit

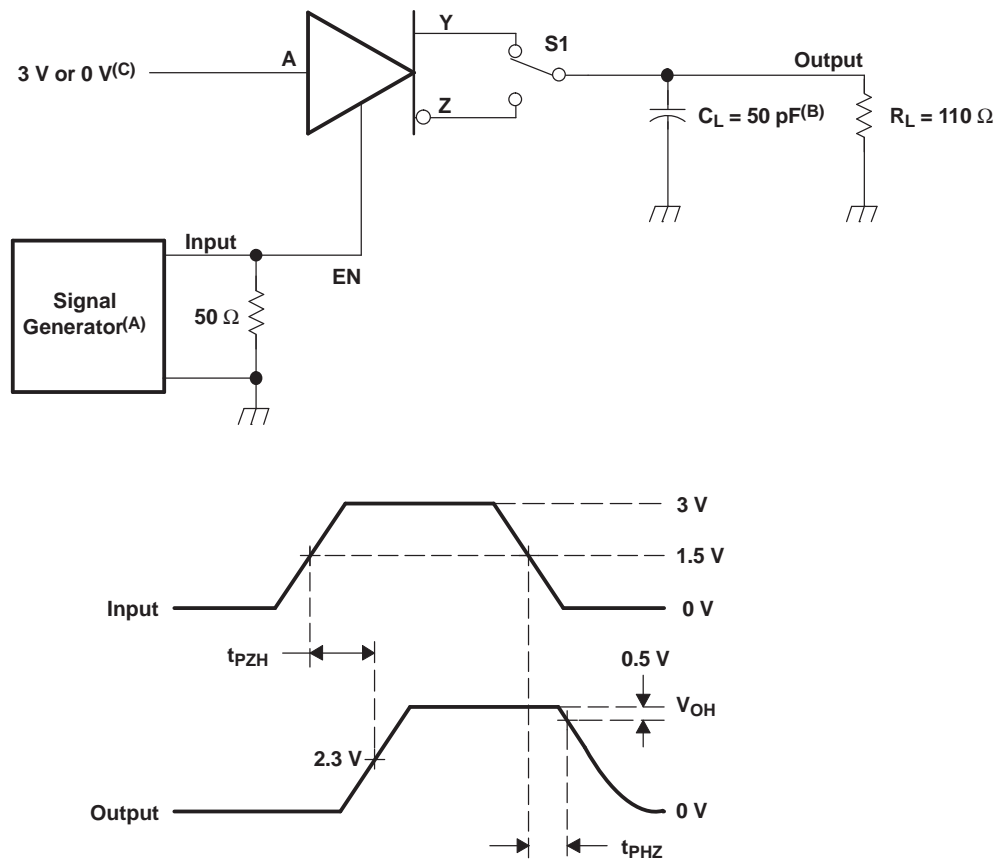
PARAMETER MEASUREMENT INFORMATION (continued)



- A. PRR = 1 MHz, 50% duty cycle, $t_r < 6$ ns, $t_f < 6$ ns, $Z_O = 50 \Omega$
- B. Includes probe and jig capacitance

Figure 4. Output Switching Test Circuit and Waveforms

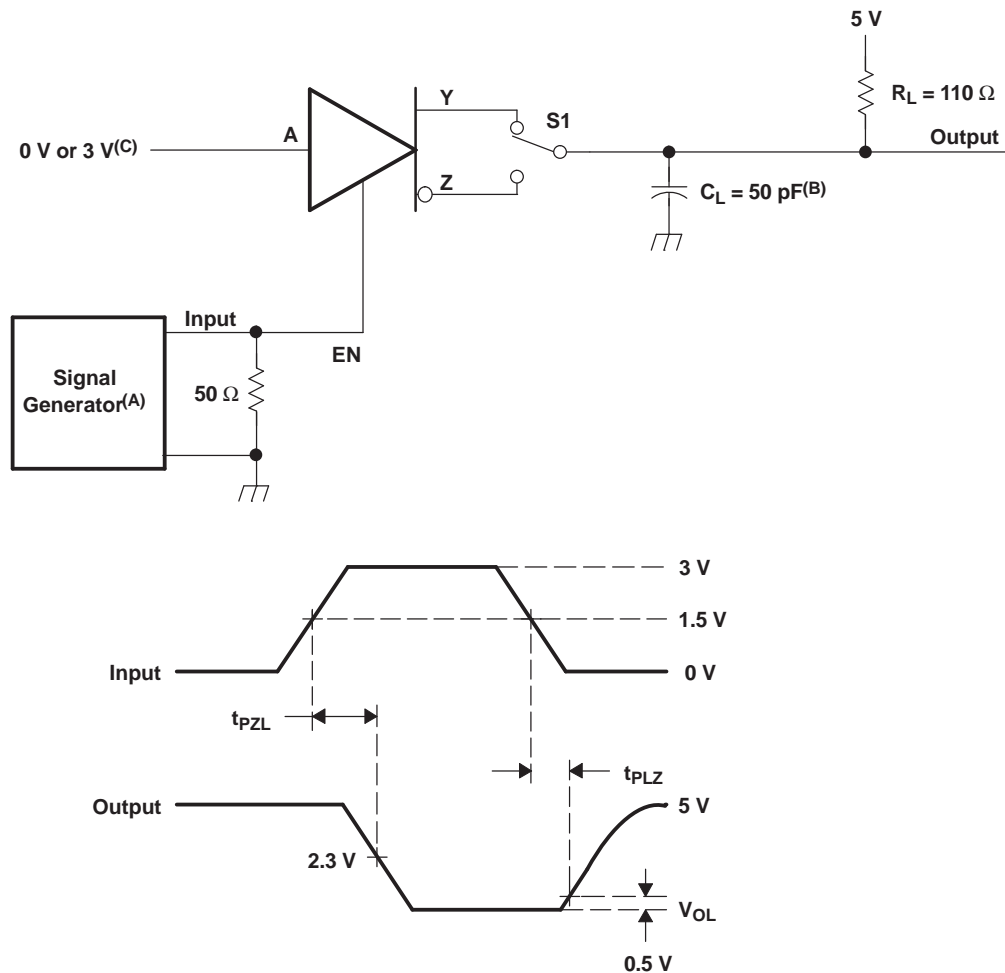
PARAMETER MEASUREMENT INFORMATION (continued)



- A. PRR = 1 MHz, 50% duty cycle, $t_r < 6 \text{ ns}$, $t_f < 6 \text{ ns}$, $Z_O = 50 \Omega$
- B. Includes probe and jig capacitance
- C. 3 V if testing Y output, 0 V if testing Z output

Figure 5. Enable Timing Test Circuit and Waveforms, t_{PZH} and t_{PHZ}

PARAMETER MEASUREMENT INFORMATION (continued)



- A. PRR = 1 MHz, 50% duty cycle, $t_r < 6 \text{ ns}$, $t_f < 6 \text{ ns}$, $Z_O = 50 \Omega$
- B. Includes probe and jig capacitance
- C. 3 V if testing Y output, 0 V if testing Z output

Figure 6. Enable Timing Test Circuit and Waveforms, t_{PZL} and t_{PLZ}

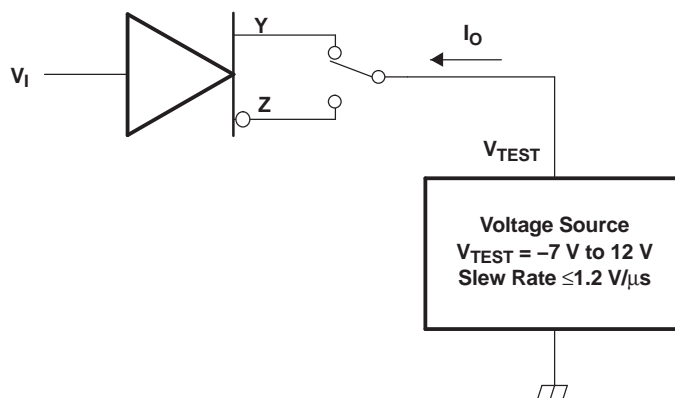


Figure 7. Test Circuit, Short-Circuit Output Current

PARAMETER MEASUREMENT INFORMATION (continued)

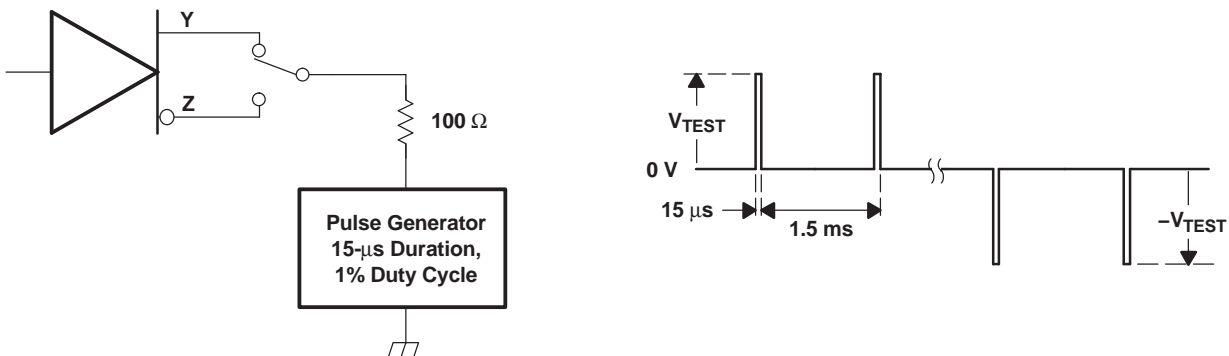


Figure 8. Test Circuit Waveform, Transient Overvoltage Test

TYPICAL CHARACTERISTICS

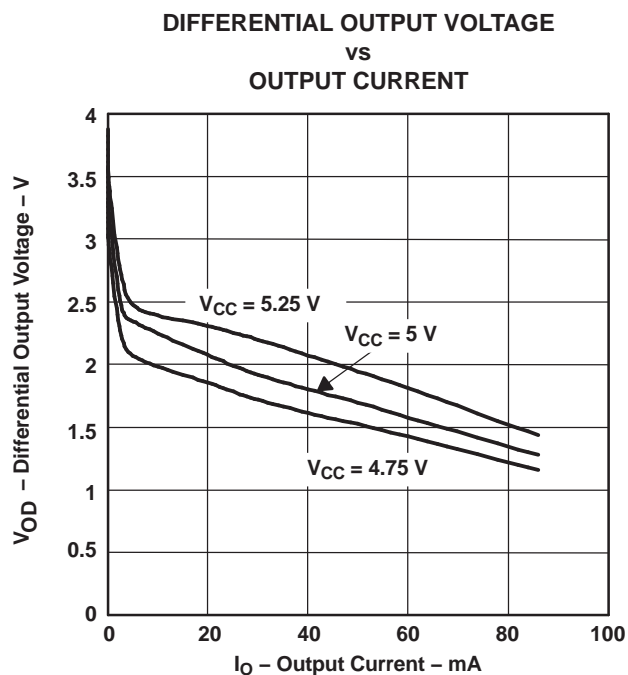


Figure 9.

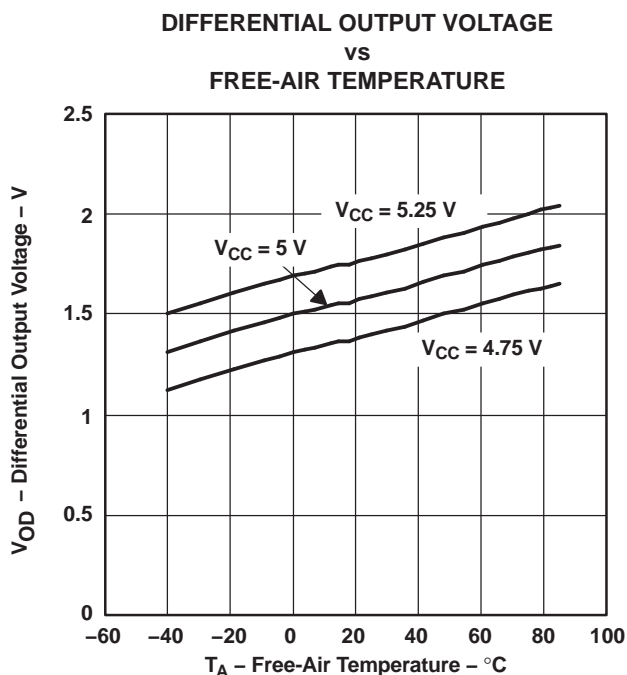


Figure 10.

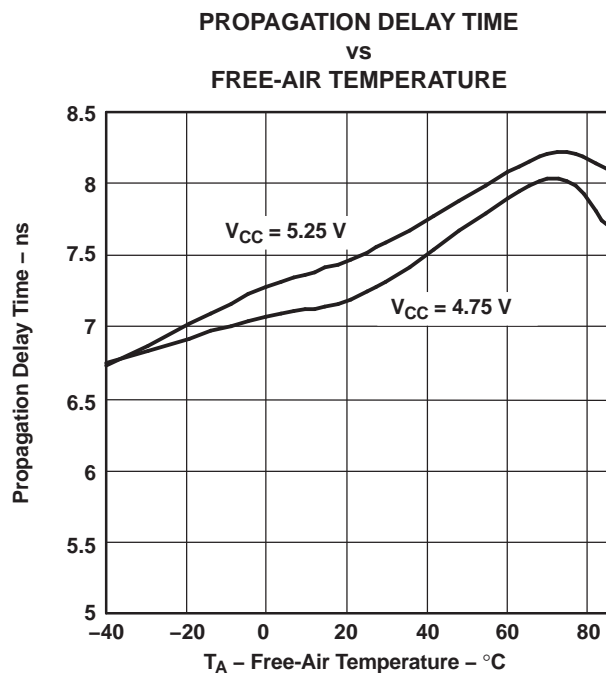


Figure 11.

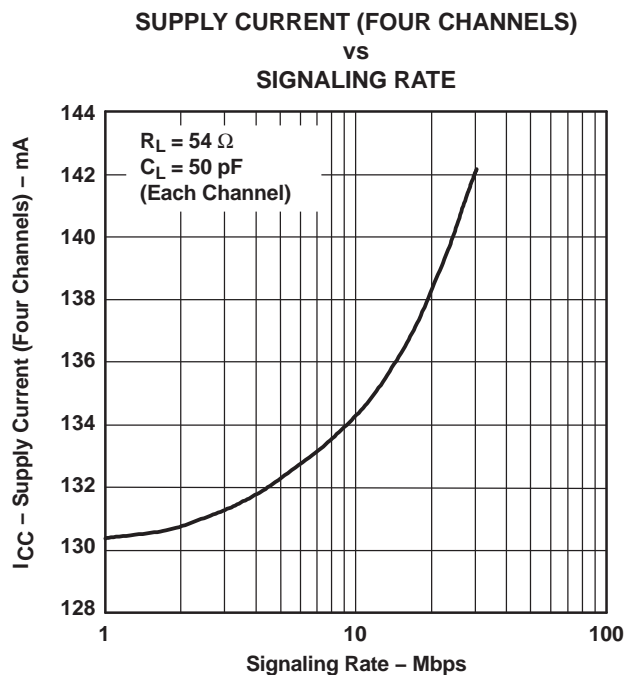


Figure 12.

TYPICAL CHARACTERISTICS (continued)

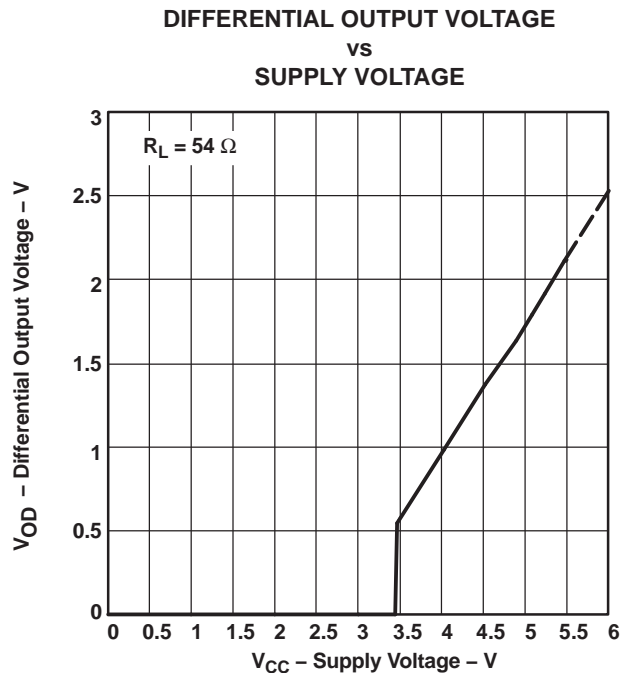


Figure 13.

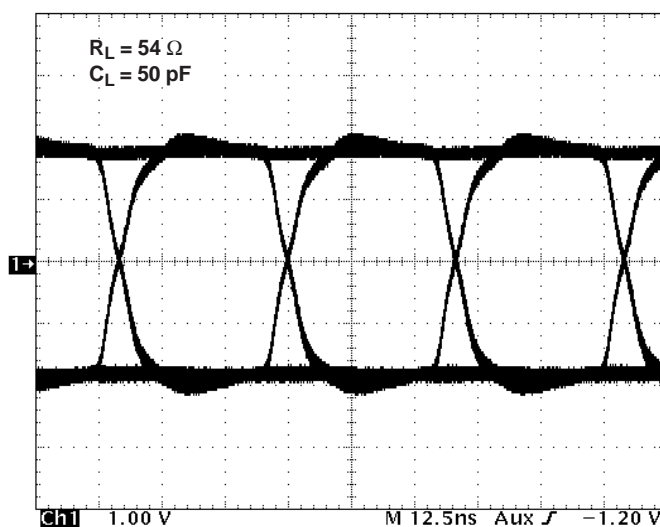


Figure 14. Eye Pattern, Pseudo-Random Data at 30 Mbps

APPLICATION INFORMATION

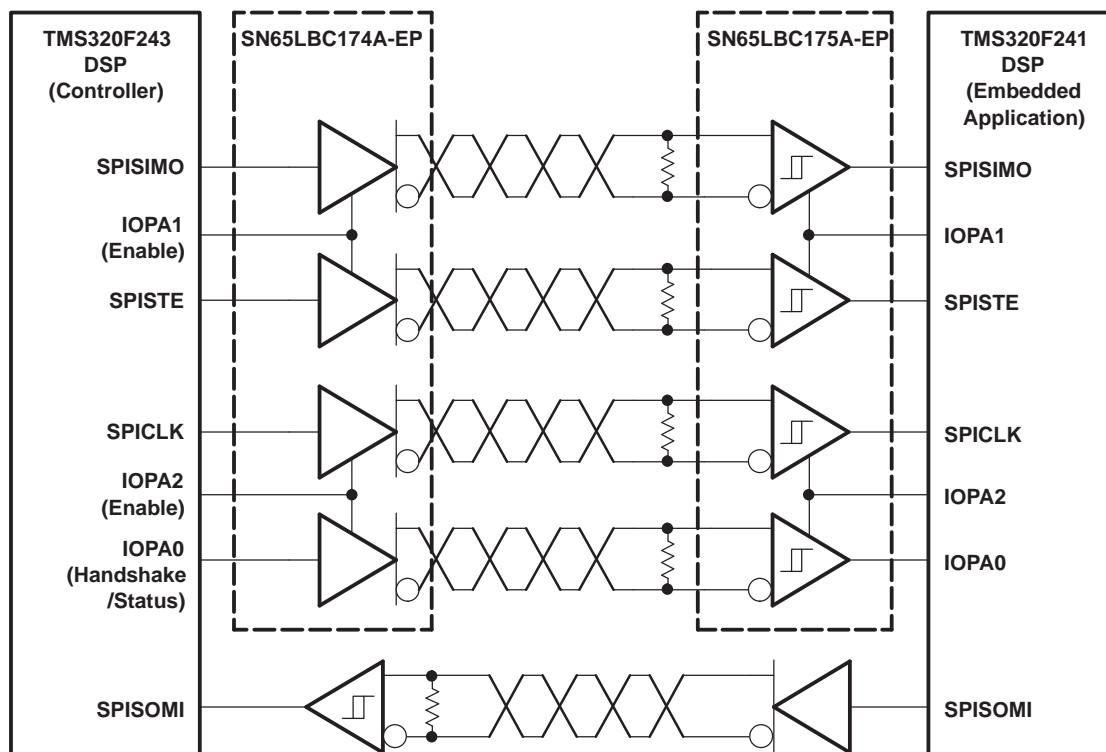


Figure 15. Typical Application Circuit, DSP-to-DSP Link Via Serial Peripheral Interface

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN65LBC174AMDWREP	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
V62/07611-01XE	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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OTHER QUALIFIED VERSIONS OF SN65LBC174A-EP :

- Catalog: [SN65LBC174A](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LBC174AMDWREP	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65LBC174AMDWREP	SOIC	DW	20	2000	367.0	367.0	45.0

DW (R-PDSO-G20)

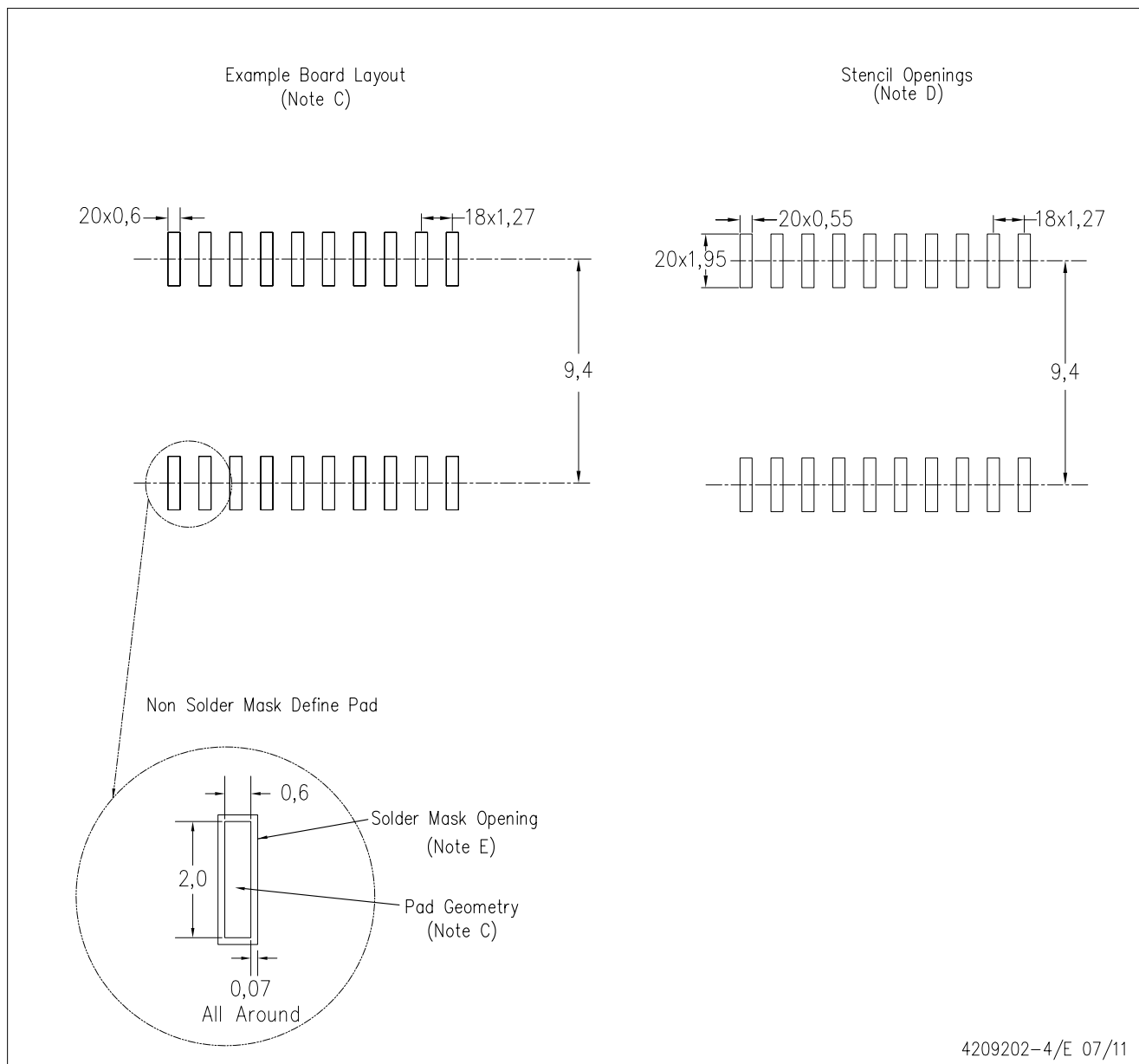
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
 - D. Falls within JEDEC MS-013 variation AC.

DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Refer to IPC7351 for alternate board design.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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